



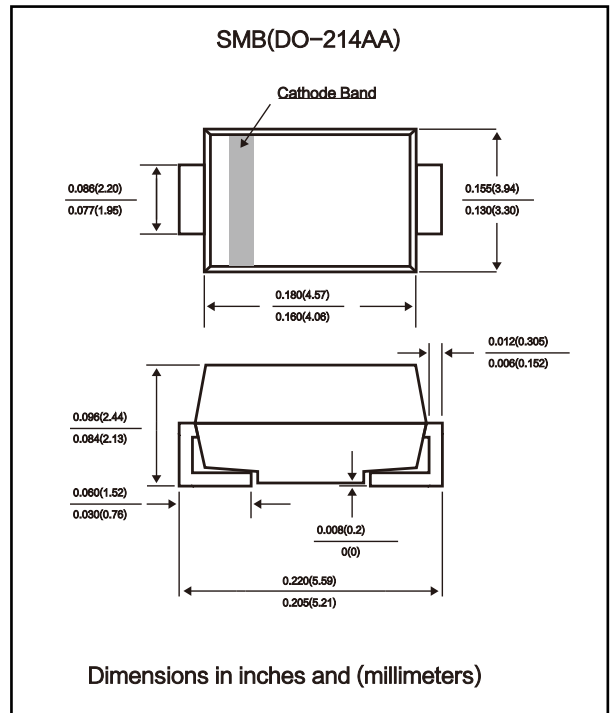
SS52 thru SS515

Features

- ◇ For surface mounted application
- ◇ Metal to silicon rectifier, majority carrier conduction
- ◇ Low forward voltage drop
- ◇ Easy pick and place
- ◇ High surge current capability
- ◇ Plastic material used carriers Underwriters Laboratory Classification 94V-0
- ◇ Epitaxial construction
- ◇ High temperature soldering: 260°C / 10 seconds at terminals

Mechanical Data

- ◇ Case: Molded plastic
- ◇ Terminals: Pure tin plated, lead free.
- ◇ Polarity: Indicated by cathode band
- ◇ Packaging: 16mm tape per EIA STD RS-481
- ◇ Weight: 0.1 gram



Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	SS 52	SS 53	SS 54	SS 55	SS 56	SS 59	SS 510	SS 515	Units	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	20	30	40	50	60	90	100	150	V	
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	63	70	105	V	
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	90	100	150	V	
Maximum Average Forward Rectified Current at T_L (See Fig. 1)	$I_{(AV)}$	5.0								A	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	120								A	
Maximum Instantaneous Forward Voltage @ 5.0A	V_F	0.55		0.75		0.85		0.95		V	
Maximum DC Reverse Current (Note 1) @ $T_A=25^\circ C$ at Rated DC Blocking Voltage @ $T_A=125^\circ C$	I_R	0.5				0.3				mA	
		20		10		5.0				mA	
Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	17								°C/W	
	$R_{\theta JA}$	55									
Operating Temperature Range	T_J	-55 to +125				-55 to +150				°C	
Storage Temperature Range	T_{STG}	-55 to +150									°C

- Notes: 1. Pulse Test with PW=300 usec, 1% Duty Cycle
2. Measured on P.C.Board with 0.6" x 0.6"(16mm x 16mm) Copper Pad Areas.



RATINGS AND CHARACTERISTIC CURVES (SS52 THRU SS515)

